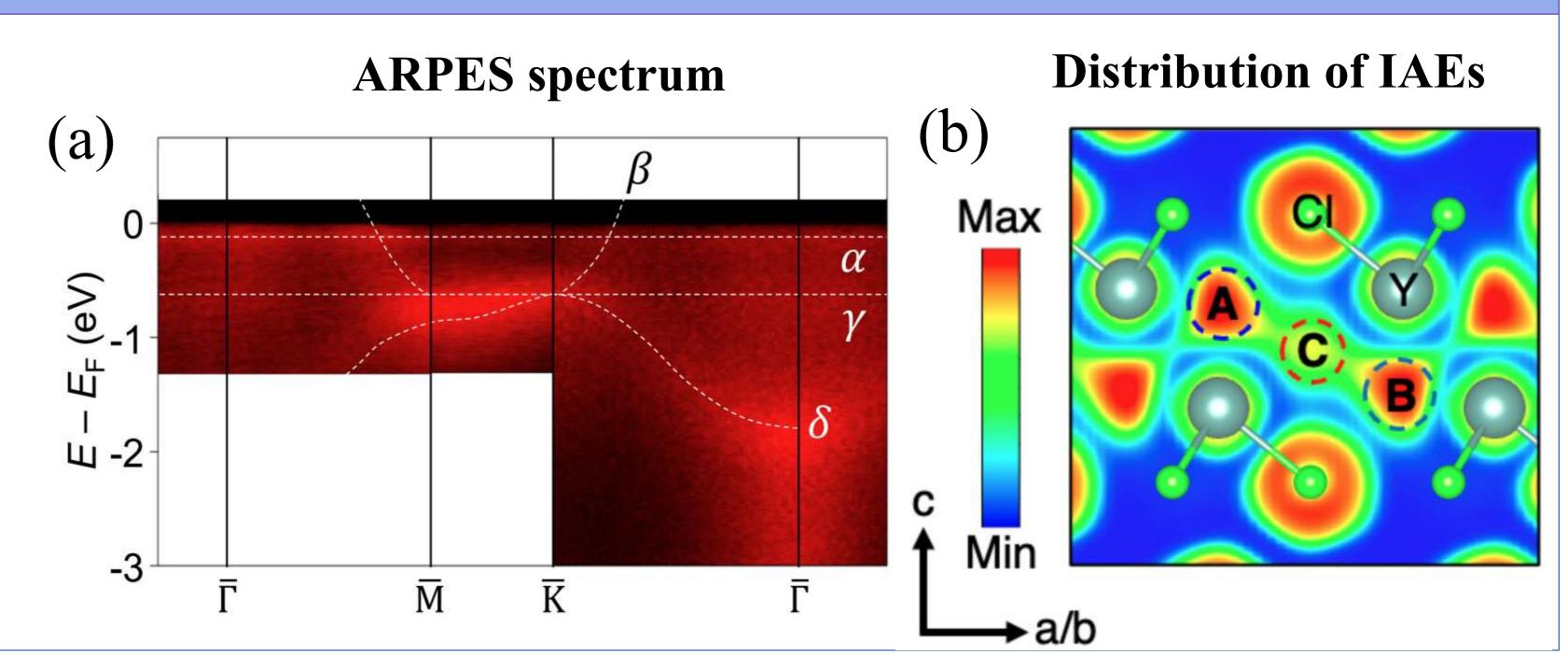
Intrinsic Topological Dice Flat Band in monolayer YCl

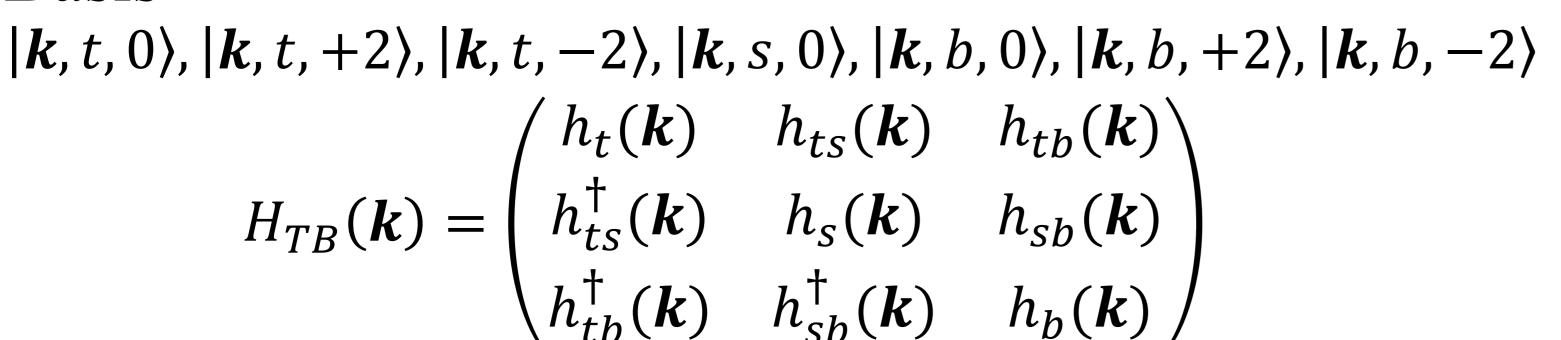
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Background

The dice lattice known for its non-dispersive (flat) band was recently realized in ARPES of YCl, which shows layered electride YCl hosts a dice geometry formed by displaced interstitial-anionic-electrons (IAEs) Wannier centers (A,B,C sublattices) and ARPES measurements unambiguously identify two sets of dice-lattice bands in YCl, including a nearly dispersionless band at the Fermi level [1].



Seven band tight-binding model (a) Top layer (A) (b) Middle layer (C) Basis



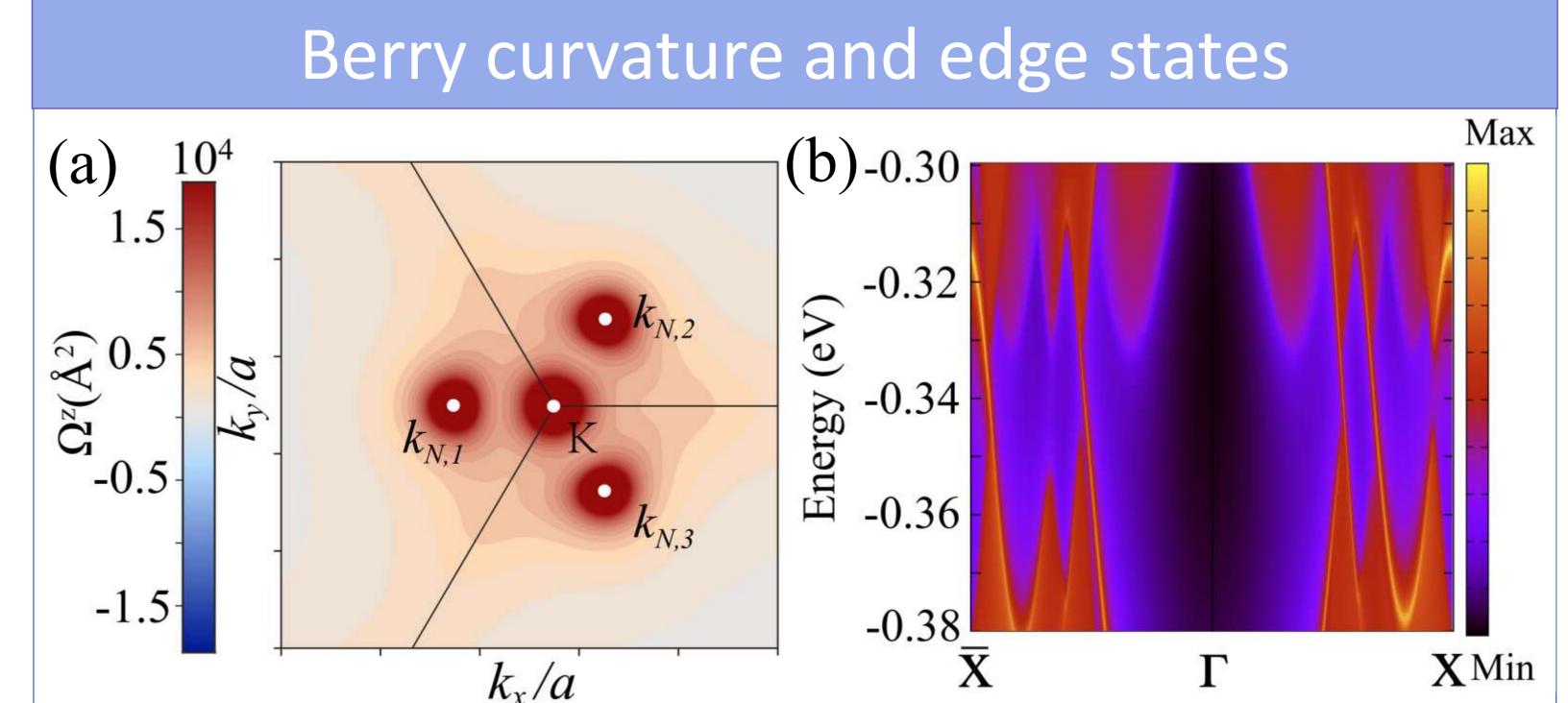
Considering three distinct generators: C_{3z} , M_x , P by symmetry constraint:

$$H_{ij} = t_{ij}(\mathbf{R}_m)e^{i\mathbf{k}\cdot(\mathbf{R}_m)}$$
$$t^{ij}(\mathbf{R}_m) = \mathbf{D}^j(R) t^{ij}(\mathbf{R}_m) \mathbf{D}^{i\dagger}(R)$$

Span the basis $|d_{+2},\uparrow\rangle$, $|d_{-2},\uparrow\rangle$, $|d_{+2},\downarrow\rangle$, $|d_{-2},\downarrow\rangle$ with the atomic SOC:

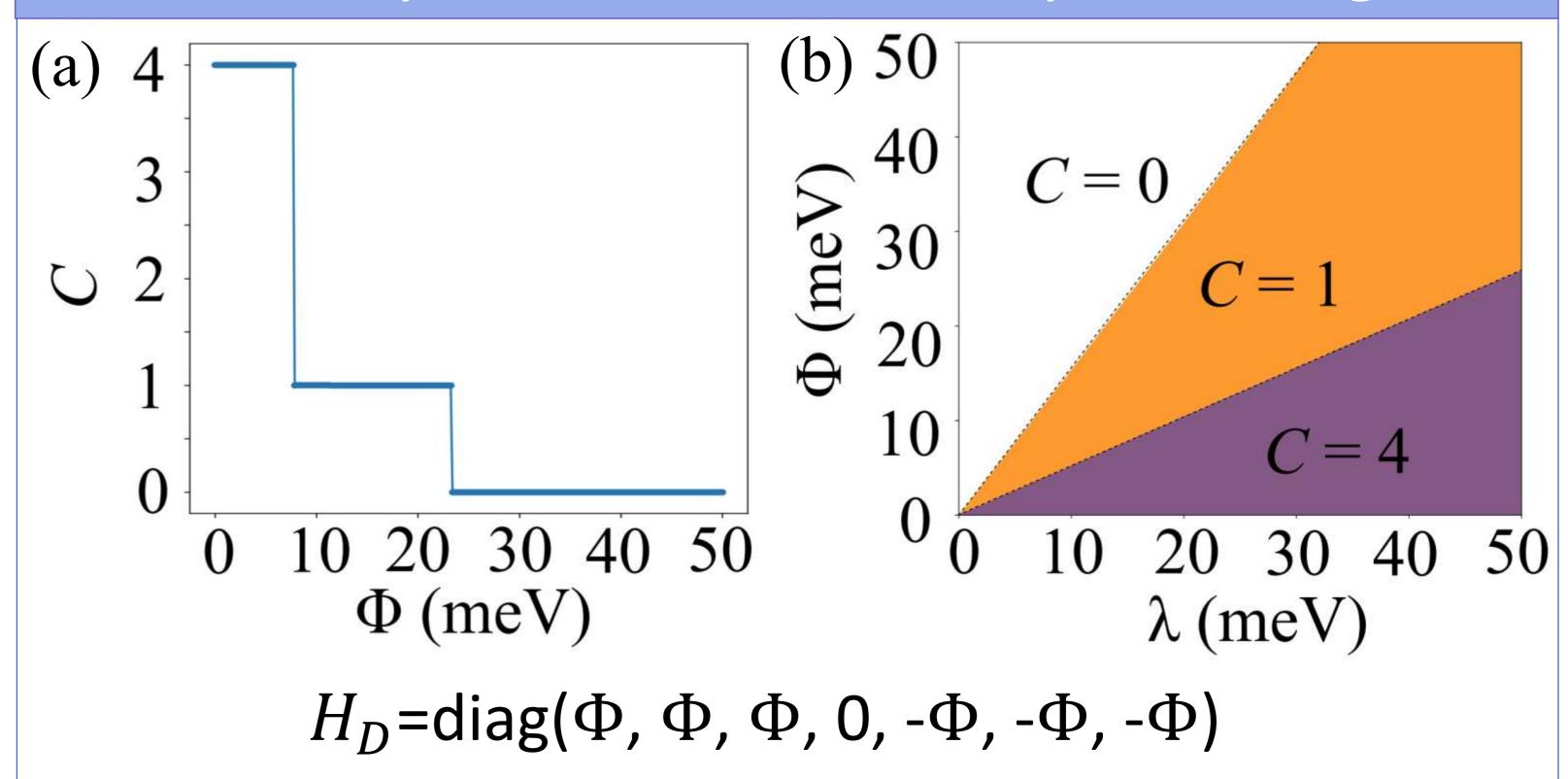
$$H_{soc} = \lambda s_z \tau_z$$

Flat band topology (a) 1.0 (c) $1.0_{\,\mathrm{T}}$ Tight-binding without SOC DFT without SOC rgy (eV) § 0.0 0.0Energy 0.1-Enei -1.0 -2.0 -2.0 (b) 1.0(d) 1.0 Tight-binding with SOC DFT with SOC Energy (eV) 0.0 0.1 Energy (eV) C = 4-0.30-0.34-0.34 -0.38-2.0K M



Four Berry curvature hot positive spots are found per valley at +K and its neighborhoods and four branches of chiral edge states in an infinite strip geometry.

Role of displacement field and phase diagram



Conclusions

- Combining symmetry analysis, fully relativistic DFT and realistic tight-binding, we find Y-4d orbital SOC gaps Dirac crossings at $\pm k$ and endows the dice flat band with $C = \pm 4$.
- The flat Chern band is intrinsic (no moiré) and its global topology and valley Berry curvature are tunable by a vertical displacement field [2].

References

[1]arXiv:2508.21311, [2] arXiv:2509.05958.